

Quad 64-/256-Position I²C[®] Nonvolatile Memory Digital Potentiometers

AD5253/AD5254

FEATURES

AD5253: guad 64-position resolution AD5254: quad 256-position resolution 1 kΩ, 10 kΩ, 50 kΩ, 100 kΩ Nonvolatile memory¹ stores wiper settings w/write protection Power-on refreshed to EEMEM settings in 300 µs typ EEMEM rewrite time = 540 μ s typ Resistance tolerance stored in nonvolatile memory 12 extra bytes in EEMEM for user-defined information I²C-compatible serial interface Direct read/write access of RDAC² and EEMEM registers Predefined linear increment/decrement commands Predefined ±6 dB step change commands Synchronous or asynchronous quad-channel update Wiper setting readback 4 MHz bandwidth—1 kΩ version Single supply 2.7 V to 5.5 V Dual supply ±2.25 V to ±2.75 V 2 slave address-decoding bits allow operation of 4 devices 100-year typical data retention, $T_A = 55^{\circ}C$ Operating temperature: -40°C to +85°C

APPLICATIONS

Mechanical potentiometer replacement Low resolution DAC replacement RGB LED backlight control White LED brightness adjustment RF base station power amp bias control Programmable gain and offset control Programmable attenuators Programmable voltage-to-current conversion Programmable power supply Programmable filters Sensor calibrations

GENERAL DESCRIPTION

The AD5253/AD5254 are quad-channel, I²C, nonvolatile memory, digitally controlled potentiometers with 64/256 positions, respectively. These devices perform the same electronic adjustment functions as mechanical potentiometers, trimmers, and variable resistors.

The parts' versatile programmability allows multiple modes of operation, including read/write access in the RDAC and EEMEM registers, increment/decrement of resistance, resistance changes in ± 6 dB scales, wiper setting readback, and extra EEMEM for storing user-defined information, such as memory data for other components, look-up table, or system identification information.

FUNCTIONAL BLOCK DIAGRAM

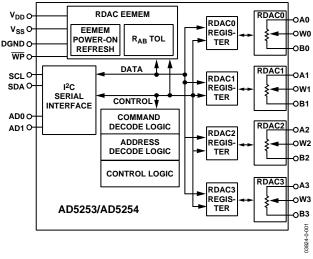


Figure 1.

The AD5253/AD5254 allow the host I²C controllers to write any of the 64-/256-step wiper settings in the RDAC registers and store them in the EEMEM. Once the settings are stored, they are restored automatically to the RDAC registers at system power-on; the settings can also be restored dynamically.

The AD5253/AD5254 provide additional increment, decrement, +6 dB step change, and -6 dB step change in synchronous or asynchronous channel update mode. The increment and decrement functions allow stepwise linear adjustments, with a \pm 6 dB step change equivalent to doubling or halving the RDAC wiper setting. These functions are useful for steep-slope, nonlinear adjustments, such as white LED brightness and audio volume control.

The AD5253/AD5254 have a patented resistance-tolerance storing function that allows the user to access the EEMEM and obtain the absolute end-to-end resistance values of the RDACs for precision applications.

The AD5253/AD5254 are available in TSSOP-20 packages in 1 k Ω , 10 k Ω , 50 k Ω , and 100 k Ω options. All parts are guaranteed to operate over the -40°C to +85°C extended industrial temperature range.

¹The terms *nonvolatile memory* and *EEMEM* are used interchangeably. ²The terms *digital potentiometer* and *RDAC* are used interchangeably.

Rev. A

Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.

 One Technology Way, P.O. Box 9106, Norwood, MA 02062-9106, U.S.A.

 Tel: 781.329.4700
 www.analog.com

 Fax: 781.461.3113
 © 2005 Analog Devices, Inc. All rights reserved.

TABLE OF CONTENTS

Features
Applications
General Description
Functional Block Diagram 1
Revision History
Electrical Characteristics
$1 \ k\Omega$ Version
10 k $\Omega,$ 50 k $\Omega,$ 100 k Ω Versions
Interface Timing Characteristics7
Absolute Maximum Ratings
ESD Caution
Pin Configuration and Function Descriptions9
Typical Performance Characteristics
I ² C Interface14
I ² C Interface General Description14
I ² C Interface Detail Description15

REVISION HISTORY

9/05—Rev. 0 to Rev. A	
Change to Figure 6	10
Change to EEMEM Write Protection Section	18
Changes to Figure 37	22
Deleted Table 13 and Table 14	24
Change to Figure 43	25
Changes to Ordering Guide	29

5/03—Revision 0: Initial Version

I ² C-Compatible 2-Wire Serial Bus	20
Theory of Operation	21
Linear Increment/Decrement Commands	21
±6 dB Adjustments (Doubling/Halving Wiper Setting)	21
Digital Input/Output Configuration	22
Multiple Devices on One Bus	22
Terminal Voltage Operation Range	23
Power-Up and Power-Down Sequences	23
Layout and Power Supply Biasing	23
Digital Potentiometer Operation	24
Programmable Rheostat Operation	24
Programmable Potentiometer Operation	25
Applications	26
RGB LED Backlight Controller for LCD Panels	26
Outline Dimensions	28
Ordering Guide	29

ELECTRICAL CHARACTERISTICS

$1 \ k\Omega \ VERSION$

 $V_{DD} = +3 \text{ V} \pm 10\% \text{ or } +5 \text{ V} \pm 10\%, V_{SS} = 0 \text{ V or } V_{DD} / V_{SS} = \pm 2.5 \text{ V} \pm 10\%, V_{A} = V_{DD}, V_{B} = 0 \text{ V}, -40^{\circ}\text{C} < T_{A} < +85^{\circ}\text{C}, \text{ unless otherwise noted.}$

Table 1.

Table 1.	Complete I		841	T 1		11
Parameter	Symbol	Conditions	Min	Typ ¹	Max	Unit
DC CHARACTERISTICS— RHEOSTAT MODE						
Resolution	N	AD5253			6	Bits
		AD5254			8	Bits
Resistor Differential Nonlinearity ²	R-DNL	R _{WB} , R _{WA} = NC, V _{DD} = 5.5 V, AD5253	-0.5	±0.2	+0.5	LSB
		R _{WB} , R _{WA} = NC, V _{DD} = 5.5 V, AD5254	-1.00	±0.25	+1.00	LSB
		R _{WB} , R _{WA} = NC, V _{DD} = 2.7 V, AD5253	-0.75	±0.30	+0.75	LSB
		R _{WB} , R _{WA} = NC, V _{DD} = 2.7 V, AD5254	-1.5	±0.3	+1.5	LSB
Resistor Nonlinearity ²	R-INL	R _{WB} , R _{WA} = NC, V _{DD} = 5.5 V, AD5253	-0.5	±0.2	+0.5	LSB
		R _{WB} , R _{WA} = NC, V _{DD} = 5.5 V, AD5254	-2.0	±0.5	+2.0	LSB
		R _{WB} , R _{WA} = NC, V _{DD} = 2.7 V, AD5253	-1.0	+2.5	+4.0	LSB
		R _{WB} , R _{WA} = NC, V _{DD} = 2.7 V, AD5254	-2	+9	+14	LSB
Nominal Resistor Tolerance	$\Delta R_{AB}/R_{AB}$	$T_A = 25^{\circ}C$	-30		+30	%
Resistance Temperature Coefficient	$(\Delta R_{AB}/R_{AB}) \times 10^{6}/\Delta T$			650		ppm/°C
Wiper Resistance	Rw	$I_W = 1 V/R, V_{DD} = 5 V$		75	130	Ω
-		$I_W = 1 V/R, V_{DD} = 3 V$		200	300	Ω
Channel-Resistance Matching	$\Delta R_{AB1} / \Delta R_{AB2}$			0.15		%
DC CHARACTERISTICS—						
POTENTIOMETER DIVIDER MODE						
Differential Nonlinearity ³	DNL	AD5253	-0.5	±0.1	+0.5	LSB
		AD5254	-1.00	±0.25	+1.00	LSB
Integral Nonlinearity ³	INL	AD5253	-0.5	±0.2	+0.5	LSB
		AD5254	-2.0	±0.5	+2.0	LSB
Voltage Divider Tempco	$(\Delta V_W/V_W) \times 10^6/\Delta T$	Code = half scale		25		ppm/°C
Full-Scale Error	V _{WFSE}	Code = full scale, V_{DD} = 5.5 V, AD5253	-5	-3	0	LSB
		Code = full scale, V_{DD} = 5.5 V, AD5254	-16	-11	0	LSB
		Code = full scale, V_{DD} = 2.7 V, AD5253	-6	-4	0	LSB
		Code = full scale, V_{DD} = 2.7 V, AD5254	-23	-16	0	LSB
Zero-Scale Error	V _{WZSE}	Code = zero scale, V_{DD} = 5.5 V, AD5253	0	3	5	LSB
		Code = zero scale, V_{DD} = 5.5 V, AD5254	0	11	16	LSB
		Code = zero scale, V_{DD} = 2.7 V, AD5253	0	4	6	LSB
		Code = zero scale, V_{DD} = 2.7 V, AD5254	0	15	20	LSB
RESISTOR TERMINALS						
Voltage Range⁴	VA, VB, VW		Vss		V _{DD}	V
Capacitance⁵ A, B	C _A , C _B	f = 1 kHz, measured to GND,		85		рF
		code = half scale				
Capacitance ⁵ W	Cw	f = 1 kHz, measured to GND,		95		рF
		code = half scale				
Common-Mode Leakage Current	Ісм	$V_A = V_B = V_{DD}/2$		0.01	1.00	μΑ
DIGITAL INPUTS AND OUTPUTS						
Input Logic High	VIH	$V_{DD} = 5 V, V_{SS} = 0 V$	2.4			V
		$V_{DD}/V_{SS} = +2.7 \text{ V/0 V or } V_{DD}/V_{SS} = \pm 2.5 \text{ V}$	2.1			V
Input Logic Low	VIL	$V_{DD} = 5 V, V_{SS} = 0 V$			0.8	V
		$V_{DD}/V_{SS} = +2.7 \text{ V/O V or } V_{DD}/V_{SS} = \pm 2.5 \text{ V}$			0.6	V
Output Logic High (SDA)	V _{OH}	$R_{\text{PULL-UP}} = 2.2 \ k\Omega$ to $V_{\text{DD}} = 5 \ \text{V}, V_{\text{SS}} = 0 \ \text{V}$	4.9			V
Output Logic Low (SDA)	Vol	$R_{PULL-UP} = 2.2 \text{ k}\Omega \text{ to } V_{DD} = 5 \text{ V}, V_{SS} = 0 \text{ V}$			0.4	V
WP Leakage Current	Iwp	$\overline{WP} = V_{DD}$			5	μΑ

Parameter	Symbol	Conditions	Min	Typ ¹	Max	Unit
A0 Leakage Current	I _{A0}	A0 = GND			3	μA
Input Leakage <u>Cur</u> rent (Other than WP and A0)	h	$V_{\text{IN}}=0 \text{ V or } V_{\text{DD}}$			±1	μA
Input Capacitance⁵	Cı			5		рF
POWER SUPPLIES						
Single-Supply Power Range	V _{DD}	$V_{SS} = 0 V$	2.7		5.5	v
Dual-Supply Power Range	V _{DD} /V _{SS}		±2.25		±2.75	v
Positive Supply Current	IDD	$V_{IH} = V_{DD} \text{ or } V_{IL} = GND$		5	15	μΑ
Negative Supply Current	lss	$\label{eq:VIH} \begin{split} V_{IH} &= V_{DD} \text{ or } V_{IL} = GND, V_{DD} = 2.5 \text{ V}, \\ V_{SS} &= -2.5 \text{ V} \end{split}$		-5	-15	μA
EEMEM Data Storing Mode Current		$V_{IH} = V_{DD} \text{ or } V_{IL} = GND$		35		mA
EEMEM Data Restoring Mode Current ⁶	IDD_RESTORE	$V_{\text{IH}} = V_{\text{DD}} \text{ or } V_{\text{IL}} = GND$		2.5		mA
Power Dissipation ⁷	P _{DISS}	$V_{IH} = V_{DD} = 5 \text{ V or } V_{IL} = GND$			0.075	mW
Power Supply Sensitivity	PSS	$\Delta V_{DD} = 5 V \pm 10\%$	-0.025	+0.010	+0.025	%/%
		$\Delta V_{DD} = 3 V \pm 10\%$	-0.04	+0.02	+0.04	%/%
DYNAMIC CHARACTERISTICS ^{5, 8}						
Bandwidth –3 dB	BW	$R_{AB} = 1 \ k\Omega$		4		MHz
Total Harmonic Distortion	THD	$V_A = 1 V rms$, $V_B = 0 V$, $f = 1 kHz$		0.05		%
V _w Settling Time	ts	$V_A = V_{DD}, V_B = 0 V$		0.2		μs
Resistor Noise Voltage	e _{N_WB}	$R_{WB} = 500 \Omega$, f = 1 kHz (thermal noise only)		3		nV/√F
Digital Crosstalk	CT	$V_A = V_{DD}$, $V_B = 0$ V, measure V_W with adjacent RDAC making full-scale change		-80		dB
Analog Coupling	C _{AT}	Signal input at A0 and measure the output at W1, $f = 1 \text{ kHz}$		-72		dB

¹ Typical values represent average readings at 25°C and $V_{DD} = 5$ V.

² Resistor position nonlinearity error (R-INL) is the deviation from an ideal value measured between the maximum and minimum resistance wiper positions. R-DNL is the relative step change from an ideal value measured between successive tap positions. Parts are guaranteed monotonic, except R-DNL of AD5254 1 k Ω version at V_{DD} = 2.7 V, I_W = V_{DD}/R for both V_{DD} = 3 V and V_{DD} = 5 V.

³ INL and DNL are measured at V_W with the RDAC configured as a potentiometer divider similar to a voltage output digital-to-analog converter. $V_A = V_{DD}$ and $V_B = 0$ V. DNL specification limits of ± 1 LSB maximum are guaranteed monotonic operating conditions.

⁴ Resistor Terminal A, Terminal B, and Terminal W have no limitations on polarity with respect to each other.

⁵ Guaranteed by design and not subject to production test.
 ⁶ Command 0 NOP should be activated after Command 1 to minimize I_{DD_RESTORE} current consumption.

 7 P_{DISS} is calculated from I_{DD} \times V_{DD} = 5 V.

⁸ All dynamic characteristics use $V_{DD} = 5$ V.

$10 \text{ k}\Omega$, $50 \text{ k}\Omega$, $100 \text{ k}\Omega$ VERSIONS

 $V_{DD} = +3 V \pm 10\%$ or $+5 V \pm 10\%$, $V_{SS} = 0 V$ or $V_{DD}/V_{SS} = \pm 2.5 V \pm 10\%$, $V_A = V_{DD}$, $V_B = 0 V$, $-40^{\circ}C < T_A < +85^{\circ}C$, unless otherwise noted. Table 2.

Table 2.	Symbol	Conditions	Min	Tun1	Max	Unit
Parameter	Symbol	Conditions	Min	Typ ¹	Max	Unit
DC CHARACTERISTICS— RHEOSTAT MODE						
Resolution	N	AD5253/AD5254			6/8	Bits
Resistor Differential Nonlinearity ²	R-DNL	R_{WB} , R_{WA} = NC, AD5253	-0.75	±0.10	+0.75	LSB
		R _{WB} , R _{WA} = NC, AD5254	-1.00	±0.25	+1.00	LSB
Resistor Nonlinearity ²	R-INL	R _{WB} , R _{WA} = NC, AD5253	-0.75	±0.25	+0.75	LSB
		R _{WB} , R _{WA} = NC, AD5254	-2.5	±1.0	+2.5	LSB
Nominal Resistor Tolerance	ΔR _{AB} /R _{AB}	$T_A = 25^{\circ}C$	-20		+20	%
Resistance Temperature Coefficient	$(\Delta R_{AB}/R_{AB}) \times 10^6/\Delta T$			650		ppm/°
Wiper Resistance	Rw	$I_W = 1 \text{ V/R}, V_{DD} = 5 \text{ V}$		75	130	Ω
		$I_W = 1 \text{ V/R}, V_{DD} = 3 \text{ V}$		200	300	Ω
Channel-Resistance Matching	$\Delta R_{AB1} / \Delta R_{AB2}$	$R_{AB} = 10 \text{ k}\Omega$, 50 $\text{k}\Omega$		0.15		%
		$R_{AB} = 100 \ k\Omega$		0.05		%
DC CHARACTERISTICS— POTENTIOMETER DIVIDER MODE						
Differential Nonlinearity ³	DNL	AD5253	-0.5	±0.1	+0.5	LSB
		AD5254	-1.0	±0.3	+1.0	LSB
Integral Nonlinearity ³	INL	AD5253	-0.50	±0.15	+0.50	LSB
		AD5254	-1.5	±0.5	+1.5	LSB
Voltage Divider Temperature Coefficient	$(\Delta V_w/V_w) \times 10^6/\Delta T$	Code = half scale		15		ppm/°
Full-Scale Error	V _{WFSE}	Code = full scale, AD5253	-1.0	-0.3	0	LSB
		Code = full scale, AD5254	-3	-1	0	LSB
Zero-Scale Error	V _{WZSE}	Code = zero scale, AD5253	0	0.3	1.0	LSB
		Code = zero scale, AD5254	0	1.2	3.0	LSB
RESISTOR TERMINALS						
Voltage Range⁴	VA, VB, VW		Vss		V _{DD}	V
Capacitance⁵ A, B	C _A , C _B	f = 1 kHz, measured to GND, code = half scale		85		pF
Capacitance ⁵ W	Cw	f = 1 kHz, measured to GND, code = half scale		95		pF
Common-Mode Leakage Current	Ісм	$V_A = V_B = V_{DD}/2$		0.01	1	μΑ
DIGITAL INPUTS AND OUTPUTS						
Input Logic High	VIH	$V_{DD} = 5 V, V_{SS} = 0 V$	2.4			V
		$V_{DD}/V_{SS} = +2.7 \text{ V/O V or } V_{DD}/V_{SS} = \pm 2.5 \text{ V}$	2.1			V
Input Logic Low	VIL	$V_{DD} = 5 V, V_{SS} = 0 V$			0.8	V
		$V_{DD}/V_{SS} = +2.7 \text{ V/O V or } V_{DD}/V_{SS} = \pm 2.5 \text{ V}$			0.6	V
Output Logic High (SDA)	V _{OH}	$R_{PULL-UP} = 2.2 \text{ k}\Omega \text{ to } V_{DD} = 5 \text{ V}, V_{SS} = 0 \text{ V}$	4.9			V
Output Logic Low (SDA)	Vol	$R_{PULL-UP} = 2.2 \text{ k}\Omega \text{ to } V_{DD} = 5 \text{ V}, V_{SS} = 0 \text{ V}$			0.4	V
WP Leakage Current	I _{WP}	$\overline{WP} = V_{DD}$			5	μA
A0 Leakage Current	I _{AO}	A0 = GND			3	μA
Input Leakage <u>Cur</u> rent (Other than WP and A0)	h	$V_{\text{IN}}=0 \text{ V or } V_{\text{DD}}$			±1	μA
Input Capacitance ⁵	C			5		рF
POWER SUPPLIES			1	1	1	† ·
Single-Supply Power Range	V _{DD}	$V_{ss} = 0 V$	2.7		5.5	v
Dual-Supply Power Range	V _{DD} /V _{SS}		±2.25		±2.75	V
Positive Supply Current	I _{DD}	$V_{IH} = V_{DD}$ or $V_{IL} = GND$	1	5	15	μA

Parameter	Symbol	Conditions	Min	Typ ¹	Max	Unit
Negative Supply Current	Iss	$\label{eq:VIH} \begin{array}{l} V_{IH} = V_{DD} \text{ or } V_{IL} = GND, V_{DD} = 2.5 \text{ V}, \\ V_{SS} = -2.5 \text{ V} \end{array}$		-5	-15	μA
EEMEM Data Storing Mode Current	IDD_STORE	$V_{IH} = V_{DD}$ or $V_{IL} = GND$, $T_A = 0^{\circ}C$ to $85^{\circ}C$		35		mA
EEMEM Data Restoring Mode Current ⁶	IDD_RESTORE	$V_{IH} = V_{DD}$ or $V_{IL} = GND$, $T_A = 0^{\circ}C$ to $85^{\circ}C$		2.5		mA
Power Dissipation ⁷	P _{DISS}	$V_{IH} = V_{DD} = 5 V \text{ or } V_{IL} = GND$			0.075	mW
Power Supply Sensitivity	PSS	$\Delta V_{\text{DD}} = 5 \text{ V} \pm 10\%$	-0.005	+0.002	+0.005	%/%
		$\Delta V_{\text{DD}} = 3 \text{ V} \pm 10\%$	-0.010	+0.002	+0.010	%/%
DYNAMIC CHARACTERISTICS ^{5, 8}						
–3 dB Bandwidth	BW	$R_{AB} = 10 \text{ k}\Omega/50 \text{ k}\Omega/100 \text{ k}\Omega$		400/80/40		kHz
Total Harmonic Distortion	THDw	$V_A = 1 V rms$, $V_B = 0 V$, $f = 1 kHz$		0.05		%
V _w Settling Time ts		$ \begin{aligned} V_A &= V_{\text{DD}}, V_B = 0 \text{ V}, \\ R_{AB} &= 10 k\Omega / 50 k\Omega / 100 k\Omega \end{aligned} $		1.5/7/14		μs
Resistor Noise Voltage e _{N_WB}		$R_{AB} = 10 \text{ k}\Omega/50 \text{ k}\Omega/100 \text{ k}\Omega$, code = midscale, f = 1 kHz (thermal noise only)		9/20/29		nV/√Hz
Digital Crosstalk C _T		$V_A = V_{DD}$, $V_B = 0$ V, measure V_W with adjacent RDAC making full-scale change		-80		dB
Analog Coupling	C _{AT}	Signal input at A0 and measure output at W1, $f = 1 \text{ kHz}$		-72		dB

 1 Typical values represent average readings at 25°C and V_{DD} = 5 V.

 2 Resistor position nonlinearity error (R-INL) is the deviation form an ideal value measured between the maximum and minimum resistance wiper positions. R-DNL is the relative step change from an ideal value measured between successive tap positions. Parts are guaranteed monotonic, except R-DNL of AD5254 1 k Ω version at V_{DD} = 2.7 V, $I_W = V_{DD}/R$ for both $V_{DD} = 3 V$ and $V_{DD} = 5 V$.

³ INL and DNL are measured at V_W with the RDAC configured as a potentiometer divider, similar to a voltage output DAC. V_A = V_{DD} and V_B = 0 V. DNL specification limits of ±1 LSB maximum are guaranteed monotonic operating conditions.

⁴ Resistor Terminal A, Terminal B, and Terminal W have no limitations on polarity with respect to each other.
 ⁵ Guaranteed by design and not subject to production test.

⁶ Command 0 NOP should be activated after Command 1 to minimize IDD_RESTORE current consumption.

⁷ P_{DISS} is calculated from $I_{DD} \times V_{DD} = 5$ V.

⁸ All dynamic characteristics use $V_{DD} = 5 V$.

INTERFACE TIMING CHARACTERISTICS

All input control voltages are specified with $t_R = t_F = 2.5$ ns (10% to 90% of 3 V) and timed from a voltage level of 1.5 V. Switching characteristics are measured using both $V_{DD} = 3$ V and 5 V.

Table 3.

Parameter ¹	Symbol	Conditions	Min	Typ ²	Max	Unit
INTERFACE TIMING						
SCL Clock Frequency	fscl				400	kHz
tBUF Bus-Free Time Between Stop and Start	t1		1.3			μs
$t_{\text{HD};\text{STA}}$ Hold Time (Repeated Start)	t ₂	After this period, the first clock pulse is generated.	0.6			μs
tLOW Low Period of SCL Clock	t3		1.3			μs
thigh High Period of SCL Clock	t4		0.6			μs
tsu;sta Set-up Time for Start Condition	t ₅		0.6			μs
t _{HD;DAT} Data Hold Time	t ₆		0		0.9	μs
tsu;DAT Data Set-up Time	t7		100			ns
t⊧ Fall Time of Both SDA and SCL Signals	t ₈				300	ns
$t_{\mbox{\tiny R}}$ Rise Time of Both SDA and SCL Signals	t9				300	ns
tsu;sto Set-up Time for Stop Condition	t10		0.6			μs
EEMEM Data Storing Time	t _{EEMEM_STORE}			26		ms
EEMEM Data Restoring Time at Power-On ³	t eemem_restore1	V_{DD} rise time dependent. Measure without decoupling capacitors at V_{DD} and V_{SS} .		300		μs
EEMEM Data Restoring Time upon Restore Command or Reset Operation ³	teemem_restore2	$V_{DD} = 5 V.$		300		μs
EEMEM Data Rewritable Time ⁴	t _{EEMEM_REWRITE}			540		μs
FLASH/EE MEMORY RELIABILITY						
Endurance⁵			100			K cycles
Data Retention ^{6, 7}				100		Years

¹ See Figure 23 for location of measured values.

 2 Typical values represent average readings at 25°C and V_{DD} = 5 V.

³ During power-up, all outputs are preset to midscale before restoring the EEMEM contents. RDAC0 has the shortest EEMEM restore time, whereas RDAC3 has the longest. ⁴ Delay time after power-on or reset before new EEMEM data to be written.

⁵ Endurance is qualified to 100,000 cycles per JEDEC Std. 22 Method A117 and measured at -40°C, +25°C, and +85°C; typical endurance at +25°C is 700,000 cycles.
 ⁶ Retention lifetime equivalent at junction temperature T_J = 55°C per JEDEC Std. 22, Method A117. Retention lifetime based on an activation energy of 0.6 eV derates with junction temperature.

⁷ When the part is not in operation, the SDA and SCL pins should be pulled high. When these pins are pulled low, the I²C interface at these pins conducts a current of about 0.8 mA at V_{DD} = 5.5 V and 0.2 mA at V_{DD} = 2.7 V.

ABSOLUTE MAXIMUM RATINGS

 $TA = 25^{\circ}C$, unless otherwise noted

Table 4.

Parameter	Rating
V _{DD} to GND	–0.3 V, +7 V
Vss to GND	+0.3 V, -7 V
V _{DD} to V _{SS}	7 V
V _A , V _B , V _W to GND	Vss, Vdd
Maximum Current	
I _{WB} , I _{WA} Pulsed	±20 mA
I_{WB} Continuous ($R_{WB} \le 1 \ k\Omega$, A Open) ¹	±5 mA
I_{WA} Continuous ($R_{WA} \le 1 \text{ k}\Omega$, B Open) ¹	±5 mA
I _{AB} Continuous	±5 mA/±500 μA/
$(R_{AB} = 1 \text{ k}\Omega/10 \text{ k}\Omega/50 \text{ k}\Omega/100 \text{ k}\Omega)^{1}$	±100 μΑ/±50 μΑ
Digital Inputs and Output Voltage to GND	0 V, 7 V
Operating Temperature Range	-40°C to +85°C
Maximum Junction Temperature (T _{JMAX})	150°C
Storage Temperature Range	–65°C to +150°C
Lead Temperature (Soldering, 10 sec)	300°C
Vapor Phase (60 sec)	215°C
Infrared (15 sec)	220°C
TSSOP-20 Thermal Resistance ² θ_{JA}	143°C/W

¹ Maximum terminal current is bound by the maximum applied voltage across any two of the A, B, and W terminals at a given resistance, the maximum current handling of the switches, and the maximum power dissipation of the package. $V_{DD} = 5$ V.

² Package power dissipation = $(T_{JMAX} - T_A)/\theta_{JA}$.

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ESD CAUTION

ESD (electrostatic discharge) sensitive device. Electrostatic charges as high as 4000 V readily accumulate on the human body and test equipment and can discharge without detection. Although this product features proprietary ESD protection circuitry, permanent damage may occur on devices subjected to high energy electrostatic discharges. Therefore, proper ESD precautions are recommended to avoid performance degradation or loss of functionality.



PIN CONFIGURATION AND FUNCTION DESCRIPTIONS

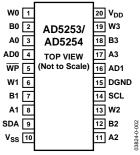
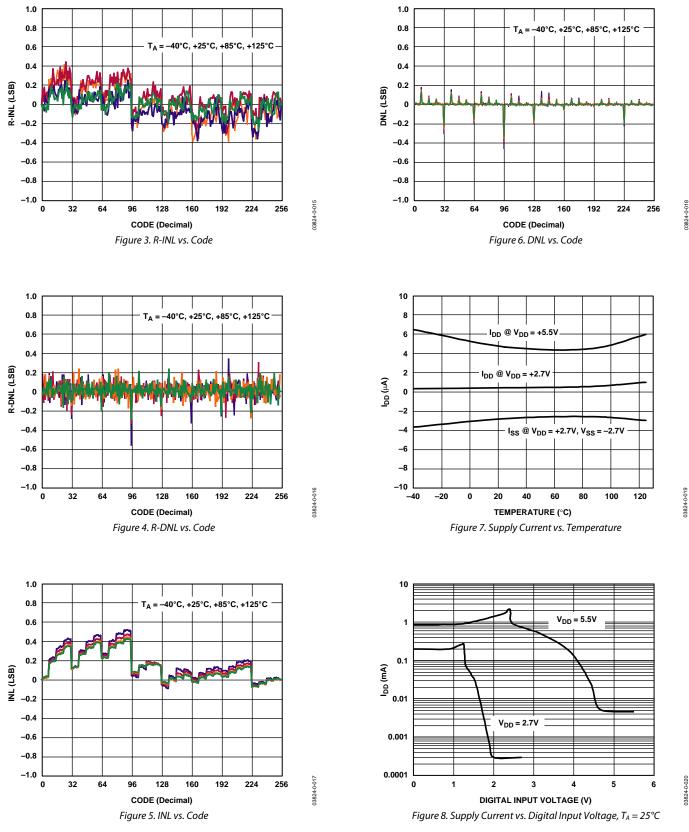


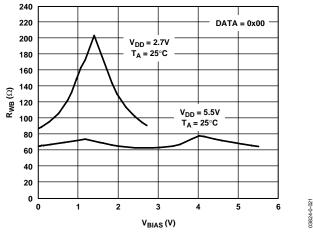
Figure 2. Pin Configuration

Table 5. Pin Function Descriptions

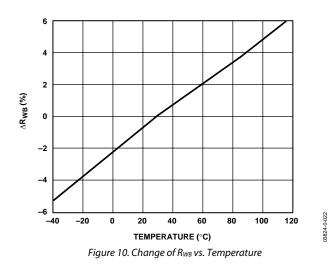
Pin No.	Mnemonic	Description
1	W0	Wiper Terminal of RDAC0. $V_{SS} \le V_{W0} \le V_{DD}$.
2	B0	B Terminal of RDAC0. $V_{SS} \le V_{B0} \le V_{DD}$.
3	A0	A Terminal of RDAC0. $V_{SS} \le V_{A0} \le V_{DD}$.
4	AD0	I ² C Device Address 0. AD0 and AD1 allow four AD5253/AD5254 devices to be addressed.
5	WP	Write Protect, Active Low. $V_{WP} \le V_{DD} + 0.3 V$.
6	W1	Wiper Terminal of RDAC1. $V_{SS} \le V_{W1} \le V_{DD}$.
7	B1	B Terminal of RDAC1. $V_{SS} \le V_{B1} \le V_{DD}$.
8	A1	A Terminal of RDAC1. $V_{SS} \le V_{A1} \le V_{DD}$.
9	SDA	Serial Data Input/Output Pin. Shifts in one bit at a time upon positive clock edges. MSB loaded first. Open-drain MOSFET requires pull-up resistor.
10	Vss	Negative Supply. Connect to 0 V for single supply or -2.7 V for dual supply, where $V_{DD} - V_{SS} \le +5.5$ V. If V_{SS} is used rather than grounded in dual supply, V_{SS} must be able to sink 35 mA for 26 ms when storing data to EEMEM.
11	A2	A Terminal of RDAC2. $V_{SS} \le V_{A2} \le V_{DD}$.
12	B2	B Terminal of RDAC2. $V_{SS} \le V_{B2} \le V_{DD}$.
13	W2	Wiper Terminal of RDAC2. $V_{SS} \le V_{W2} \le V_{DD}$.
14	SCL	Serial Input Register Clock Pin. Shifts in one bit at a time upon positive clock edges. $V_{SCL} \le (V_{DD} + 0.3 \text{ V})$. Pull-up resistor is recommended for SCL to ensure minimum power.
15	DGND	Digital Ground. Connect to system analog ground at a single point.
16	AD1	I ² C Device Address 1. AD0 and AD1 allow four AD5253/AD5254 devices to be addressed.
17	A3	A Terminal of RDAC3. $V_{SS} \le V_{A3} \le V_{DD}$.
18	B3	B Terminal of RDAC3. $V_{SS} \le V_{B3} \le V_{DD}$.
19	W3	Wiper Terminal of RDAC3. $V_{SS} \le V_{W3} \le V_{DD}$.
20	V _{DD}	Positive Power Supply Pin. Connect +2.7 V to +5 V for single supply or ± 2.7 V for dual supply, where $V_{DD} - V_{SS} \le +5.5$ V. V_{DD} must be able to source 35 mA for 26 ms when storing data to EEMEM.











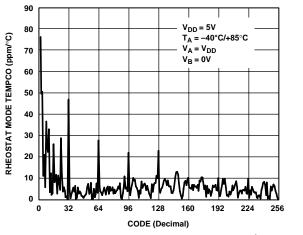


Figure 11. Rheostat Mode Tempco $(\Delta R_{WB}/R_{WB})/\Delta T \times 10^6$ vs. Code

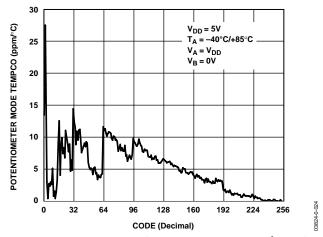
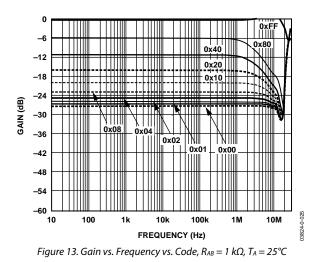


Figure 12. Potentiometer Mode Tempco ($\Delta V_{WB}/V_{WB}$)/ $\Delta T \times 10^6$ vs. Code



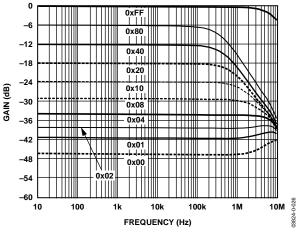
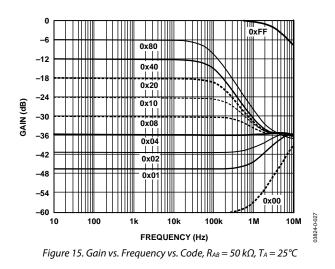
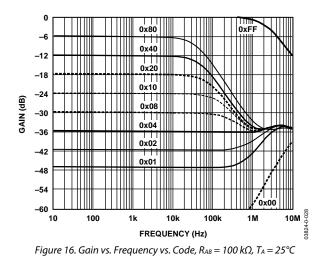
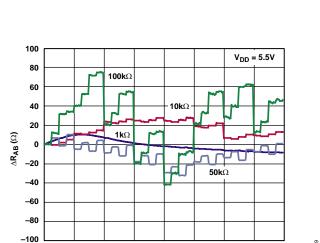


Figure 14. Gain vs. Frequency vs. Code, $R_{AB} = 10 k\Omega$, $T_A = 25^{\circ}C$

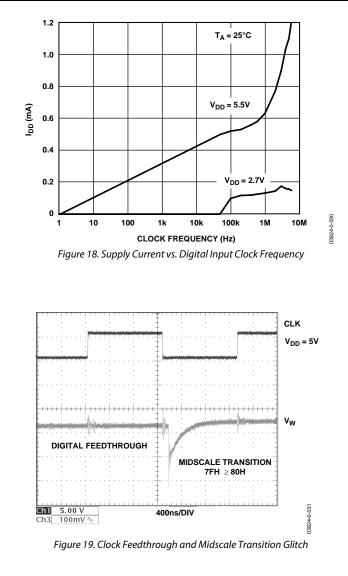
03824-0-023

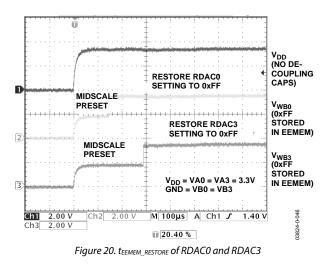






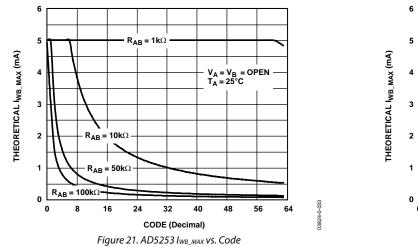
CODE (Decimal) Figure 17. ΔR_{AB} vs. Code, $T_A = 25^{\circ}C$

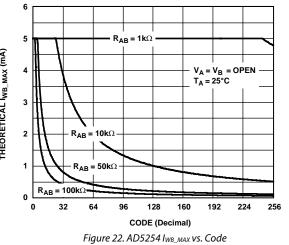




3824-0-025

03824-0-034





I²C INTERFACE

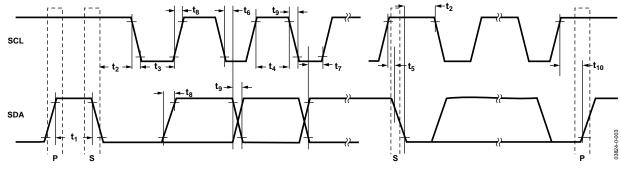


Figure 23. I²C Interface Timing Diagram

I²C INTERFACE GENERAL DESCRIPTION



From Slave to Master

- S = start condition
- P = stop condition
- A = acknowledge (SDA low)
- \overline{A} = not acknowledge (SDA high)

 R/\overline{W} = read enable at high; write enable at low

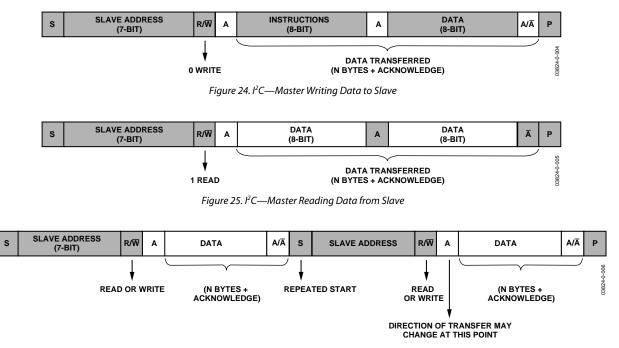


Figure 26. I²C—Combined Write/Read

I²C INTERFACE DETAIL DESCRIPTION

From Master to Slave

From Slave to Master

S = start condition

P = stop condition

 $\underline{A} = acknowledge (SDA low)$

 \overline{A} = not acknowledge (SDA high)

AD1, AD0 = I²C device address bits, must match with the logic states at Pins AD1, AD0

 R/\overline{W} = read enable bit at logic high; write enable bit at logic low

 CMD/\overline{REG} = command enable bit at logic high; register access bit at logic low

 EE/\overline{RDAC} = EEMEM register at logic high; RDAC register at logic low

A4, A3, A2, A1, A0 = RDAC/EEMEM register addresses

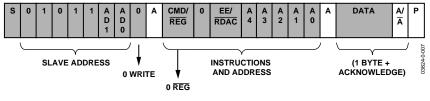


Figure 27. Single Write Mode

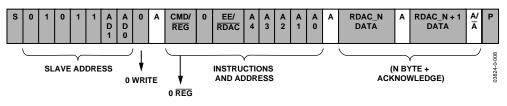




Table 6. Addresses for Writing Data Byte Contents to RDAC Registers (R/W = 0, $CMD/\overline{REG} = 0$, $EE/\overline{RDAC} = 0$)

A4	A3	A2	A1	A0	RDAC	Data Byte Description
0	0	0	0	0	RDAC0	6-/8-bit wiper setting (2 MSB of AD5253 are X)
0	0	0	0	1	RDAC1	6-/8-bit wiper setting (2 MSB of AD5253 are X)
0	0	0	1	0	RDAC2	6-/8-bit wiper setting (2 MSB of AD5253 are X)
0	0	0	1	1	RDAC3	6-/8-bit wiper setting (2 MSB of AD5253 are X)
0	0	1	0	0	Reserved	
:	:	:	:	:	:	
:	:	:	:	:	:	
0	1	1	1	1	Reserved	

RDAC/EEMEM Write

Setting the wiper position requires an RDAC write operation. The single write operation is shown in Figure 27, and the consecutive write operation is shown in Figure 28. In the consecutive write operation, if the RDAC is selected and the address starts at 0, the first data byte goes to RDAC0, the second data byte goes to RDAC1, the third data byte goes to RDAC2, and the fourth data byte goes to RDAC3. This operation can be continued for up to eight addresses with four unused addresses; it then loops back to RDAC0. If the address starts at any of the eight valid addresses, N, the data first goes to RDAC2, N, RDAC_N + 1, and so on; it loops back to RDAC0 after the eighth address. The RDAC address is shown in Table 6.

While the RDAC wiper setting is controlled by a specific RDAC register, each RDAC register corresponds to a specific EEMEM location, which provides nonvolatile wiper storage functionality. The addresses are shown in Table 7. The single and consecutive write operations also apply to EEMEM write operations.

There are 12 nonvolatile memory locations: EEMEM4 to EEMEM15. Users can store 12 bytes of information, such as memory data for other components, look-up tables, or system identification information.

In a write operation to the EEMEM registers, the device disables the I²C interface during the internal write cycle. Acknowledge polling is required to determine the completion of the write cycle. See the EEMEM Write-Acknowledge Polling section.

RDAC/EEMEM Read

The AD5253/AD5254 provide two different RDAC or EEMEM read operations. For example, Figure 29 shows the method of reading the RDAC0 to RDAC3 contents without specifying the address, assuming Address RDAC0 was already selected in the previous operation. If an RDAC_N address other than RDAC0 was previously selected, readback starts with Address N, followed by N + 1, and so on.

Figure 30 illustrates a random RDAC or EEMEM read operation. This operation allows users to specify which RDAC or EEMEM register is read by issuing a dummy write command to change the RDAC address pointer and then proceeding with the RDAC read operation at the new address location. Table 7. Addresses for Writing (Storing) RDAC Settings and User-Defined Data to EEMEM Registers $(R/W = 0, CMD/\overline{REG} = 0, EE/\overline{RDAC} = 1)$

•					-
A4	A3	A2	A1	A0	Data Byte Description
0	0	0	0	0	Store RDAC0 setting to EEMEM0 ¹
0	0	0	0	1	Store RDAC1 setting to EEMEM1 ¹
0	0	0	1	0	Store RDAC2 setting to EEMEM2 ¹
0	0	0	1	1	Store RDAC3 setting to EEMEM3 ¹
0	0	1	0	0	Store user data to EEMEM4
0	0	1	0	1	Store user data to EEMEM5
0	0	1	1	0	Store user data to EEMEM6
0	0	1	1	1	Store user data to EEMEM7
0	1	0	0	0	Store user data to EEMEM8
0	1	0	0	1	Store user data to EEMEM9
0	1	0	1	0	Store user data to EEMEM10
0	1	0	1	1	Store user data to EEMEM11
0	1	1	0	0	Store user data to EEMEM12
0	1	1	0	1	Store user data to EEMEM13
0	1	1	1	0	Store user data to EEMEM14
0	1	1	1	1	Store user data to EEMEM15

 Table 8. Addresses for Reading (Restoring) RDAC Settings

 and User Data from EEMEM

1	D/TAT 1	CMD/DDC ($\mathbf{b}, \mathbf{EE}/\mathbf{RDAC} = 1$
L	$\mathbf{K} / \mathbf{W} = \mathbf{I}$	(MI)/RE(4 = 0) $EE/RDA(=1)$
ſ	10/00 - 13	Om D/RLO = 0	J $L L (L L L L L L L L L L L L L L L L L$

A4	A3	A2	A1	A0	Data Byte Description		
0	0	0	0	0	Read RDAC0 setting from EEMEM0		
0	0	0	0	1	Read RDAC1 setting from EEMEM1		
0	0	0	1	0	Read RDAC2 setting from EEMEM2		
0	0	0	1	1	Read RDAC3 setting from EEMEM3		
0	0	1	0	0	Read User data from EEMEM4		
0	0	1	0	1	Read user data from EEMEM5		
0	0	1	1	0	Read user data from EEMEM6		
0	0	1	1	1	Read user data from EEMEM7		
0	1	0	0	0	Read user data from EEMEM8		
0	1	0	0	1	Read user data from EEMEM9		
0	1	0	1	0	Read user data from EEMEM10		
0	1	0	1	1	Read user data from EEMEM11		
0	1	1	0	0	Read user data from EEMEM12		
0	1	1	0	1	Read user data from EEMEM13		
0	1	1	1	0	Read user data from EEMEM14		
0	1	1	1	1	Read user data from EEMEM15		

¹ Users can store any of the 64 RDAC settings for AD5253 or any of the 256 RDAC settings for the AD5254 directly to the EEMEM. This is not limited to current RDAC wiper setting.

From Master to Slave

From Slave to Master

- S = start condition
- P = stop condition
- $\underline{A} = acknowledge (SDA low)$
- \overline{A} = not acknowledge (SDA high)

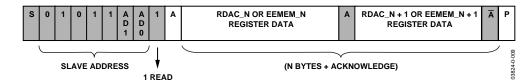
AD1, $AD0 = I^2C$ device address bits, must match with the logic states at Pins AD1, AD0

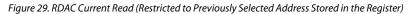
 R/\overline{W} = read enable bit at logic high; write enable bit at logic low

 CMD/\overline{REG} = command enable bit at logic high; register access bit at logic low

C3, C2, C1, C0 = command bits

A2, *A1*, *A0* = RDAC/EEMEM register addresses





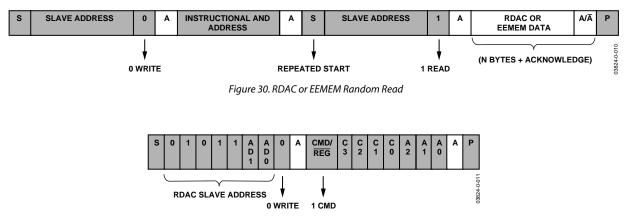


Figure 31. RDAC Quick Command Write (Dummy Write)

RDAC/EEMEM Quick Commands

The AD5253/AD5254 feature 12 quick commands that facilitate easy manipulation of RDAC wiper settings and provide RDACto-EEMEM storing and restoring functions. The command format is shown in Figure 31, and the command descriptions are shown in Table 9.

When using a quick command, issuing a third byte is not needed, but is allowed. The quick commands reset and store RDAC to EEMEM require acknowledge polling to determine whether the command has finished executing.

R_{AB} Tolerance Stored in Read-Only Memory

The AD5253/AD5254 feature patented R_{AB} tolerances storage in the nonvolatile memory. The tolerance of each channel is stored in the memory during the factory production and can be read by users at any time. The knowledge of the stored tolerance, which is the average of R_{AB} over all codes (see Figure 16), allows users to predict R_{AB} accurately. This feature is valuable for precision, rheostat mode, and open-loop applications, in which knowledge of absolute resistance is critical.

The stored tolerances reside in the read-only memory and are expressed as percentages. Each tolerance is 16 bits long and is stored in two memory locations (see Table 10). The tolerance data is expressed in sign magnitude binary format stored in two bytes; an example is shown in Figure 32. For the first byte in Register N, the MSB is designated for the sign (0 = + and 1 = -) and the 7 LSB is designated for the integer portion of the tolerance. For the second byte in Register N + 1, all eight data

bits are designated for the decimal portion of tolerance. As shown in Table 10 and Figure 32, for example, if the rated R_{AB} is 10 k Ω and the data readback from Address 11000 shows 0001 1100 and Address 11001 shows 0000 1111, then RDAC0 tolerance can be calculated as

$$\begin{split} MSB: 0 &= + \\ Next \ 7 \ MSB: \ 001 \ 1100 &= 28 \\ 8 \ LSB: \ 0000 \ 1111 &= 15 \times 2^{-8} &= 0.06 \\ Tolerance &= 28.06\% \ and, \ therefore, \\ R_{AB_ACTUAL} &= 12.806 \ k\Omega \end{split}$$

EEMEM Write-Acknowledge Polling

After each write operation to the EEMEM registers, an internal write cycle begins. The I²C interface of the device is disabled. To determine if the internal write cycle is complete and the I²C interface is enabled, interface polling can be executed. I²C interface polling can be conducted by sending a start condition followed by the slave address and the write bit. If the I²C interface responds with an ACK, the write cycle is complete and the interface is ready to proceed with further operations. Otherwise, I²C interface polling can be repeated until it succeeds. Command 2 and Command 7 also require acknowledge polling.

EEMEM Write Protection

Setting the \overline{WP} pin to logic low after EEMEM programming protects the memory and RDAC registers from future write operations. In this mode, the EEMEM and RDAC read operations function as normal.

C3	C2	C1	C0	Command Description
0	0	0	0	NOP
0	0	0	1	Restore EEMEM (A1, A0) to RDAC (A1, A0) ¹
0	0	1	0	Store RDAC (A1, A0) to EEMEM (A1, A0)
0	0	1	1	Decrement RDAC (A1, A0) 6 dB
0	1	0	0	Decrement all RDACs 6 dB
0	1	0	1	Decrement RDAC (A1, A0) one step
0	1	1	0	Decrement all RDACs one step
0	1	1	1	Reset: restore EEMEMs to all RDACs
1	0	0	0	Increment RDACs (A1, A0) 6 dB
1	0	0	1	Increment all RDACs 6 dB
1	0	1	0	Increment RDACs (A1, A0) one step
1	0	1	1	Increment all RDACs one step
1	1	0	0	Reserved
:	:	:	:	:
:	:	:	:	
1	1	1	1	Reserved

Table 9. RDAC-to-EEMEM Interface and RDAC Operation Quick Command Bits (CMD/REG = 1, A2 = 0)

¹ This command leaves the device in the EEMEM read power state, which consumes power. Issue the NOP command to return the device to its idle state.

A4	A3	A2	A1	A0	Data Byte Description	
1	1	0	0	0	Sign and 7-bit integer values of RDAC0 tolerance (read only)	
1	1	0	0	1	8-bit decimal value of RDAC0 tolerance (read only)	
1	1	0	1	0	ign and 7-bit integer values of RDAC1 tolerance (read only)	
1	1	0	1	1	8-bit decimal value of RDAC1 tolerance (read only)	
1	1	1	0	0	Sign and 7-bit integer values of RDAC2 tolerance (read only)	
1	1	1	0	1	8-bit decimal value of RDAC2 tolerance (read only)	
1	1	1	1	0	Sign and 7-bit integer values of RDAC3 tolerance (read only)	
1	1	1	1	1	8-bit decimal value of RDAC3 tolerance (read only)	

Table 10. Address Table for Reading Tolerance (CMD/ $\overline{\text{REG}} = 0$, $\overline{\text{EE}/\text{RDAC}} = 1$, A4 = 1)

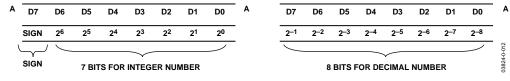
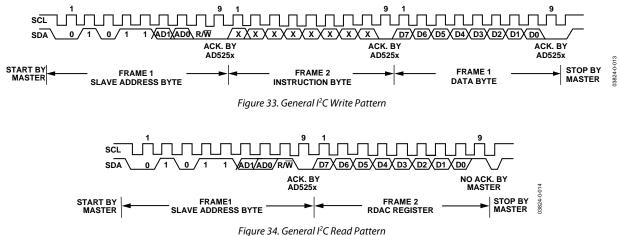


Figure 32. Format of Stored Tolerance in Sign Magnitude Format with Bit Position Descriptions (Unit is Percent, Only Data Bytes Are Shown)

I²C-COMPATIBLE 2-WIRE SERIAL BUS



The first byte of the AD5253/AD5254 is a slave address byte (see Figure 33 and Figure 34). It has a 7-bit slave address and an R/\overline{W} bit. The 5 MSB of the slave address is 01011, and the next 2 LSB is determined by the states of the AD1 and AD0 pins. AD1 and AD0 allow the user to place up to four AD5253/AD5254 devices on one bus.

AD5253/AD5254 can be controlled via an I²C-compatible serial bus and are connected to this bus as slave devices. The 2-wire I²C serial bus protocol (see Figure 33 and Figure 34) follows:

1. The master initiates a data transfer by establishing a start condition, such that SDA goes from high to low while SCL is high (see Figure 33). The following byte is the slave address byte, which consists of the 5 MSB of a slave address defined as 01011. The next two bits are AD1 and AD0, I^2C device address bits. Depending on the states of their AD1 and AD0 bits, four AD5253/AD5254 devices can be addressed on the same bus. The last LSB, the R/\overline{W} bit, determines whether data is read from or written to the slave device.

The slave whose address corresponds to the transmitted address responds by pulling the SDA line low during the ninth clock pulse (this is called an acknowledge bit). At this stage, all other devices on the bus remain idle while the selected device waits for data to be written to or read from its serial register.

2. In the write mode (except when restoring EEMEM to the RDAC register), there is an instruction byte that follows the slave address byte. The MSB of the instruction byte is labeled CMD/REG. MSB = 1 enables CMD, the command instruction byte; MSB = 0 enables general register writing. The third MSB in the instruction byte, labeled EE/RDAC, is true when MSB = 0 or when the device is in general writing mode. EE enables the EEMEM register, and REG

enables the RDAC register. The 5 LSB, A4 to A0, designates the addresses of the EEMEM and RDAC registers (see Figure 27 and Figure 28). When MSB = 1 or when the device is in CMD mode, the four bits following the MSB are C3 to C1, which correspond to 12 predefined EEMEM controls and quick commands; there are also four factoryreserved commands. The 3 LSB—A2, A1, and A0—are 4channel RDAC addresses (see Figure 31). After acknowledging the instruction byte, the last byte in the write mode is the data byte. Data is transmitted over the serial bus in sequences of nine clock pulses (eight data bits followed by an acknowledge bit). The transitions on the SDA line must occur during the low period of SCL and remain stable during the high period of SCL (see Figure 33).

- 3. In current read mode, the RDAC0 data byte immediately follows the acknowledgment of the slave address byte. After an acknowledgement, RDAC1 follows, then RDAC2, and so on. (There is a slight difference in write mode, where the last eight data bits representing RDAC3 data are followed by a no acknowledge bit.) Similarly, the transitions on the SDA line must occur during the low period of SCL and remain stable during the high period of SCL (see Figure 34). Another reading method, random read method, is shown in Figure 30.
- 4. When all data bits have been read or written, a stop condition is established by the master. A stop condition is defined as a low-to-high transition on the SDA line that occurs while SCL is high. In write mode, the master pulls the SDA line high during the 10th clock pulse to establish a stop condition (see Figure 33). In read mode, the master issues a no acknowledge for the ninth clock pulse, that is, the SDA line remains high. The master brings the SDA line low before the 10th clock pulse and then brings the SDA line high to establish a stop condition (see Figure 34).

THEORY OF OPERATION

The AD5253/AD5254 are quad-channel digital potentiometers in 1 k Ω , 10 k Ω , 50 k Ω , or 100 k Ω that allow 64/256 linear resistance step adjustments. The AD5253/AD5254 employ doublegate CMOS EEPROM technology, which allows resistance settings and user-defined data to be stored in the EEMEM registers. The EEMEM is nonvolatile, such that settings remain when power is removed. The RDAC wiper settings are restored from the nonvolatile memory settings during device power-up and can also be restored at any time during operation.

The AD5253/AD5254 resistor wiper positions are determined by the RDAC register contents. The RDAC register acts like a scratch-pad register, allowing unlimited changes of resistance settings. RDAC register contents can be changed using the device's serial I²C interface. The format of the data-words and the commands to program the RDAC registers are discussed in the I²C Interface section.

The four RDAC registers have corresponding EEMEM memory locations that provide nonvolatile storage of resistor wiper position settings. The AD5253/AD5254 provide commands to store the RDAC register contents to their respective EEMEM memory locations. During subsequent power-on sequences, the RDAC registers are automatically loaded with the stored value.

Whenever the EEMEM write operation is enabled, the device activates the internal charge pump and raises the EEMEM cell gate bias voltage to a high level; this essentially erases the current content in the EEMEM register and allows subsequent storage of the new content. Saving data to an EEMEM register consumes about 35 mA of current and lasts approximately 26 ms. Because of charge-pump operation, all RDAC channels may experience noise coupling during the EEMEM writing operation.

The EEMEM restore time in power-up or during operation is about 300 μ s. Note that the power-up EEMEM refresh time depends on how fast V_{DD} reaches its final value. As a result, any supply voltage decoupling capacitors limit the EEMEM restore time during power-up. For example, Figure 20 shows the power-up profile of the V_{DD} where there is no decoupling capacitors and the applied power is a digital signal. The device initially resets the RDACs to midscale before restoring the EEMEM contents. The omission of the decoupling capacitors should only be considered when the fast restoring time is absolutely needed in the application. In addition, users should issue a NOP Command 0 immediately after using Command 1 to restore the EEMEM setting to RDAC, thereby minimizing supply current dissipation. Reading user data directly from EEMEM does not require a similar NOP command execution.

In addition to the movement of data between RDAC and EEMEM registers, the AD5253/AD5254 provide other shortcut commands that facilitate programming, as shown in Table 11.

Command	Description		
0	NOP.		
1	Restore EEMEM content to RDAC. User should issue NOP immediately after this command to conserve power.		
2	Store RDAC register setting to EEMEM.		
3	Decrement RDAC 6 dB (shift data bits right).		
4	Decrement all RDACs 6 dB (shift all data bits right).		
5	Decrement RDAC one step.		
6	Decrement all RDACs one step.		
7	Reset EEMEM contents to all RDACs.		
8	Increment RDAC 6 dB (shift data bits left).		
9	Increment all RDACs 6 dB (shift all data bits left).		
10	Increment RDAC one step.		
11	Increment all RDACs one step.		
12 to 15	Reserved.		

Table 11. Quick Commands

LINEAR INCREMENT/DECREMENT COMMANDS

The increment and decrement commands (10, 11, 5, and 6) are useful for linear step-adjustment applications. These commands simplify microcontroller software coding by allowing the controller to send just an increment or decrement command to the AD5253/AD5254. The adjustments can be directed to a single RDAC or to all four RDACs.

±6 dB ADJUSTMENTS (DOUBLING/HALVING WIPER SETTING)

The AD5253/AD5254 accommodate ±6 dB adjustments of the RDAC wiper positions by shifting the register contents to left/ right for increment/decrement operations, respectively. Command 3, Command 4, Command 8, and Command 9 can be used to increment or decrement the wiper positions in 6 dB steps synchronously or asynchronously.

Incrementing the wiper position by +6 dB essentially doubles the RDAC register value, whereas decrementing the wiper position by -6 dB halves the register content. Internally, the AD5253/AD5254 use shift registers to shift the bits left and right to achieve a \pm 6 dB increment or decrement. The maximum number of adjustments is nine and eight steps for incrementing from zero scale and decrementing from full scale, respectively. These functions are useful for various audio/video level adjustments, especially for white LED brightness settings in which human visual responses are more sensitive to large adjustments than to small adjustments.

DIGITAL INPUT/OUTPUT CONFIGURATION

SDA is a digital input/output with an open-drain MOSFET that requires a pull-up resistor for proper communication. On the other hand, SCL and \overline{WP} are digital inputs for which pull-up resistors are recommended to minimize the MOSFET crossconduction current when the driving signals are lower than V_{DD} . SCL and \overline{WP} have ESD protection diodes, as shown in Figure 35 and Figure 36.

 $\overline{\text{WP}}$ can be permanently tied to V_{DD} without a pull-up resistor if the write-protect feature is not used. If $\overline{\text{WP}}$ is left floating, an internal current source pulls it low to enable write protection. In applications in which the device is programmed infrequently, this allows the part to default to write-protection mode after any one-time factory programming or field calibration without using an on-board pull-down resistor. Because there are protection diodes on all inputs, the signal levels must not be greater than V_{DD} to prevent forward biasing of the diodes.

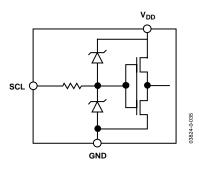


Figure 35. SCL Digital Input

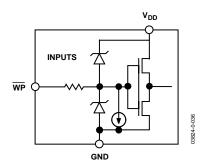


Figure 36. Equivalent WP Digital Input

MULTIPLE DEVICES ON ONE BUS

The AD5253/AD5254 are equipped with two addressing pins, AD1 and AD0, that allow up to four AD5253/AD5254 devices to be operated on one I²C bus. To achieve this result, the states of AD1 and AD0 on each device must first be defined. An example is shown in Table 12 and Figure 37. In I²C programming, each device is issued a different slave address—01011(AD1)(AD0)— to complete the addressing.

AD1	AD0	Device Addressed	
0	0	U1	
0	1	U2	
1	0	U3	
1	1	U4	

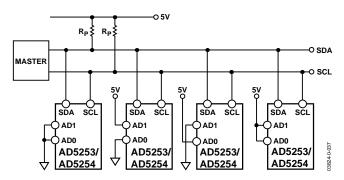


Figure 37. Multiple AD5253/AD5254 Devices on a Single Bus

In wireless base station smart-antenna systems that require arrays of digital potentiometers to bias the power amplifiers, large numbers of AD5253/AD5254 devices can be addressed by using extra decoders, switches, and I/O buses, as shown in Figure 38. For example, to communicate to a total of 16 devices, four decoders and 16 sets of combinational switches (four sets shown in Figure 38) are needed. Two I/O buses serve as the common inputs of the four 2×4 decoders and select four sets of outputs at each combination. Because the four sets of combination switch outputs are unique, as shown in Figure 38, a specific device is addressed by properly programming the I²C with the slave address defined as 01011(AD1)(AD0). This operation allows one of 16 devices to be addressed, provided that the inputs of the two decoders do not change states. The inputs of the decoders are allowed to change once the operation of the specified device is completed.

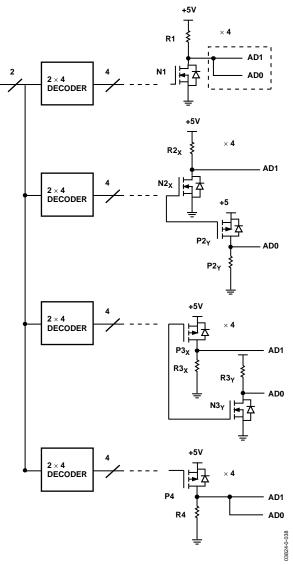


Figure 38. Four Devices with AD1 and AD0 of 00

TERMINAL VOLTAGE OPERATION RANGE

The AD5253/AD5254 are designed with internal ESD diodes for protection; these diodes also set the boundaries for the terminal operating voltages. Positive signals present on Terminal A, Terminal B, or Terminal W that exceed V_{DD} are clamped by the forward-biased diode. Similarly, negative signals on Terminal A, Terminal B, or Terminal W that are more negative than V_{SS} are also clamped (see Figure 39). In practice, users should not operate V_{AB}, V_{WA}, and V_{WB} to be higher than the voltage across V_{DD} to V_{SS}, but V_{AB}, V_{WA}, and V_{WB} have no polarity constraint.

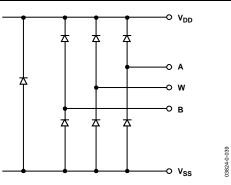


Figure 39. Maximum Terminal Voltages Set by VDD and Vss

POWER-UP AND POWER-DOWN SEQUENCES

Because the ESD protection diodes limit the voltage compliance at Terminal A, Terminal B, and Terminal W (Figure 39), it is important to power V_{DD}/V_{SS} before applying any voltage to these terminals. Otherwise, the diodes are forward biased such that V_{DD}/V_{SS} are powered unintentionally and may affect the user's circuit. Similarly, V_{DD}/V_{SS} should be powered down last. The ideal power-up sequence is in the following order: GND, V_{DD} , V_{SS} , digital inputs, and $V_A/V_B/V_W$. The order of powering V_A , V_B , V_W , and the digital inputs is not important, as long as they are powered after V_{DD}/V_{SS} .

LAYOUT AND POWER SUPPLY BIASING

It is always a good practice to employ a compact, minimum lead-length layout design. The leads to the input should be as direct as possible, with a minimum conductor length. Ground paths should have low resistance and low inductance.

Similarly, it is also good practice to bypass the power supplies with quality capacitors. Low equivalent series resistance (ESR) 1 μ F to 10 μ F tantalum or electrolytic capacitors should be applied at the supplies to minimize any transient disturbance and filter low frequency ripple. Figure 40 illustrates the basic supply-bypassing configuration for the AD5253/AD5254.

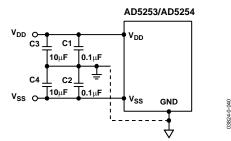


Figure 40. Power Supply-Bypassing Configuration

The ground pin of the AD5253/AD5254 is used primarily as a digital ground reference. To minimize the digital ground bounce, the AD5253/AD5254 ground terminal should be joined remotely to the common ground (see Figure 40).

DIGITAL POTENTIOMETER OPERATION

The structure of the RDAC is designed to emulate the performance of a mechanical potentiometer. The RDAC contains a string of resistor segments with an array of analog switches that act as the wiper connection to the resistor array. The number of points is the resolution of the device. For example, the AD5253/AD5254 emulate 64/256 connection points with 64/256 equal resistance, Rs, allowing them to provide better than 1.5%/0.4% resolution.

Figure 41 provides an equivalent diagram of the connections between the three terminals that make up one channel of the RDAC. Switches SW_A and SW_B are always on, but only one of switches SW(0) to SW(2^{N-1}) can be on at a time (determined by the setting decoded from the data bit). Because the switches are nonideal, there is a 75 Ω wiper resistance, R_w. Wiper resistance is a function of supply voltage and temperature: Lower supply voltages and higher temperatures result in higher wiper resistances. Consideration of wiper resistance dynamics is important in applications in which accurate prediction of output resistance is required.

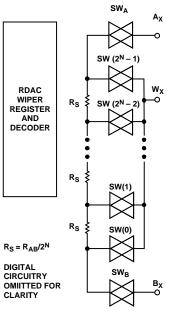


Figure 41. Equivalent RDAC Structure

PROGRAMMABLE RHEOSTAT OPERATION

If either the W-to-B or W-to-A terminal is used as a variable resistor, the unused terminal can be opened or shorted with W; such operation is called rheostat mode (see Figure 42). The resistance tolerance can range $\pm 20\%$.

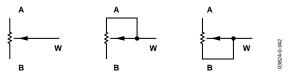


Figure 42. Rheostat Mode Configuration

The nominal resistance of the AD5253/AD5254 has 64/256 contact points accessed by the wiper terminal, plus the B terminal contact. The 6-/8-bit data-word in the RDAC register is decoded to select one of the 64/256 settings. The wiper's first connection starts at the B terminal for Data 0x00. This B terminal connection has a wiper contact resistance, Rw, of 75 Ω , regardless of the nominal resistance. The second connection (the AD5253 10 k Ω part) is the first tap point where RwB = 231 Ω (RwB = RAB/64 + Rw = 156 Ω + 75 Ω) for Data 0x01, and so on. Each LSB data value increase moves the wiper up the resistor ladder until the last tap point is reached at RwB = 9893 Ω . See Figure 41 for a simplified diagram of the equivalent RDAC circuit.

The general equation that determines the digitally programmed output resistance between W and B is

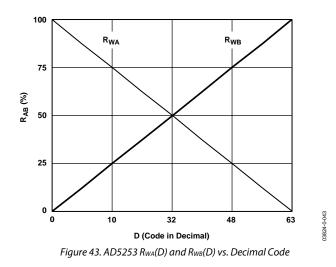
AD5253: RWB(D) =
$$(D/64) \times RAB + 75 \Omega$$
 (1)

AD5254: RWB(D) =
$$(D/256) \times RAB + 75 \Omega$$
 (2)

where:

D is the decimal equivalent of the data contained in the RDAC latch.

 R_{AB} is the nominal end-to-end resistance.



Since the digital potentiometer is not ideal, a 75 Ω finite wiper resistance is present that can easily be seen when the device is programmed at zero scale. Because of the fine geometric and interconnects employed by the device, care should be taken to limit the current conduction between W and B to no more than ±5 mA continuous for a total resistance of 1 k Ω or a pulse of ±20 mA to avoid degradation or possible destruction of the device. The maximum dc current for AD5253 and AD5254 are shown in Figure 21 and Figure 22, respectively.

Similar to the mechanical potentiometer, the resistance of the RDAC between Wiper W and Terminal A also produces a digitally controlled complementary resistance, R_{WA} . When these terminals are used, the B terminal can be opened. The R_{WA} starts at a maximum value and decreases as the data loaded into the latch increases in value (see Figure 43. The general equation for this operation is

AD5253: RWA(D) =
$$[(64 - D)/64] \times RAB + 75 \Omega$$
 (3)

AD5254: RWA(D) =
$$[(256 - D)/256] \times RAB + 75 \Omega$$
 (4)

The typical distribution of R_{AB} from channel-to-channel matches is about ±0.15% within a given device. On the other hand, device-to-device matching is process-lot dependent with a ±20% tolerance.

PROGRAMMABLE POTENTIOMETER OPERATION

If all three terminals are used, the operation is called potentiometer mode (see Figure 44); the most common configuration is the voltage divider operation.

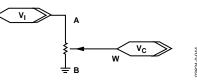


Figure 44. Potentiometer Mode Configuration

If the wiper resistance is ignored, the transfer function is simply

AD5253:
$$V_W = \frac{D}{64} \times V_{AB} + V_B \tag{5}$$

AD5254:
$$V_W = \frac{D}{256} \times V_{AB} + V_B \tag{6}$$

A more accurate calculation that includes the wiper resistance effect is

$$V_{W}(D) = \frac{\frac{D}{2^{N}}R_{AB} + R_{W}}{R_{AB} + 2R_{W}}V_{A}$$
(7)

where 2^N is the number of steps.

Unlike in rheostat mode operation, where the tolerance is high, potentiometer mode operation yields an almost ratiometric function of $D/2^N$ with a relatively small error contributed by the R_W terms. Therefore, the tolerance effect is almost cancelled. Similarly, the ratiometric adjustment also reduces the temperature coefficient effect to 50 ppm/°C, except at low value codes where R_W dominates.

Potentiometer mode operations include other applications such as op amp input, feedback-resistor networks, and other voltage-scaling applications. The A, W, and B terminals can, in fact, be input or output terminals, provided that $|V_A|$, $|V_W|$, and $|V_B|$ do not exceed V_{DD} to V_{SS} .

APPLICATIONS RGB LED BACKLIGHT CONTROLLER FOR LCD PANELS

Because high power (>1 W) RGB LEDs offer superior color quality compared with cold cathode florescent lamps (CCFLs) as backlighting sources, it is likely that high-end LCD panels will employ RGB LEDs as backlight in the near future. Unlike conventional LEDs, high power LEDs have a forward voltage of 2 V to 4 V and consume more than 350 mA at maximum brightness. The LED brightness is a linear function of the conduction current, but not of the forward voltage. To increase the brightness of a given color, multiple LEDs can be connected in series, rather than in parallel, to achieve uniform brightness. For example, three red LEDs configured in series require an average of 6 V to 12 V headroom, but the circuit operation requires current control. As a result, Figure 45 shows the implementation of one high power RGB LED controller using a AD5254, a boost regulator, an op amp, and power MOSFETs. The ADP1610 (U2 in Figure 45) is an adjustable boost regulator with its output adjusted by the AD5254's RDAC3. Such an output should be set high enough for proper operation but low enough to conserve power. The ADP1610's 1.2 V band gap reference is buffered to provide the reference level for the voltage dividers set by the AD5254's RDAC0 to RDAC2 and Resistor R2 to Resistor R4. For example, by adjusting the AD5254's RDAC0, the desirable voltage appears across the sense resistors, R_R. If U2's output is set properly, op amp U3A and power MOSFET N1 do whatever is necessary to regulate the current of the loop. As a result, the current through the sense resistor and the red LEDs is

$$I_R = \frac{V_{RR}}{R_R} \tag{8}$$

R8 is needed to prevent oscillation.

In addition to the 256 levels of adjustable current/brightness, users can also apply a PWM signal at U3's $\overline{\text{SD}}$ pin to achieve finer brightness resolution or better power efficiency.

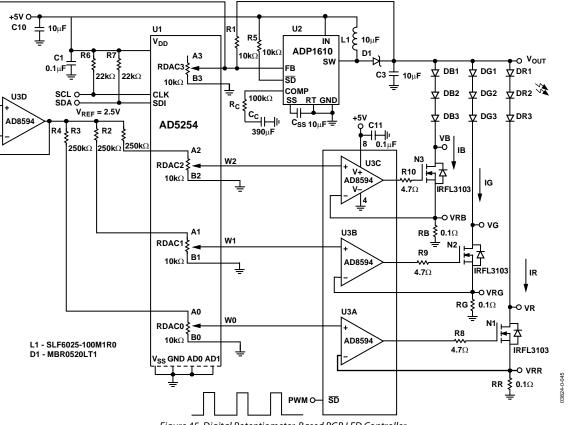
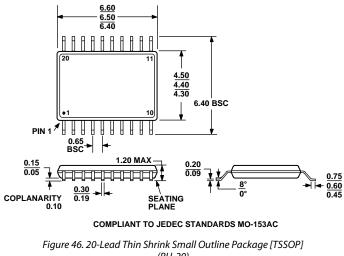


Figure 45. Digital Potentiometer-Based RGB LED Controller

OUTLINE DIMENSIONS



(RU-20) Dimensions shown in millimeters

ORDERING GUIDE

Model ¹	Step	R _{AB} (kΩ)	Temperature Range (°C)	Package Description	Package Option	Ordering Quantity
AD5253BRU1	64	1	-40 to +85	20-Lead TSSOP	RU-20	75
AD5253BRU1-RL7	64	1	-40 to +85	20-Lead TSSOP	RU-20	1,000
AD5253BRUZ1 ²	64	1	-40 to +85	20-Lead TSSOP	RU-20	75
AD5253BRUZ1-RL7 ²	64	1	-40 to +85	20-Lead TSSOP	RU-20	1,000
AD5253BRU10	64	10	-40 to +85	20-Lead TSSOP	RU-20	75
AD5253BRU10-RL7	64	10	-40 to +85	20-Lead TSSOP	RU-20	1,000
AD5253BRUZ10 ²	64	10	-40 to +85	20-Lead TSSOP	RU-20	75
AD5253BRUZ10-RL7 ²	64	10	-40 to +85	20-Lead TSSOP	RU-20	1,000
AD5253BRU50	64	50	-40 to +85	20-Lead TSSOP	RU-20	75
AD5253BRU50-RL7	64	50	-40 to +85	20-Lead TSSOP	RU-20	1,000
AD5253BRUZ50 ²	64	50	-40 to +85	20-Lead TSSOP	RU-20	75
AD5253BRUZ50-RL7 ²	64	50	-40 to +85	20-Lead TSSOP	RU-20	1,000
AD5253BRU100	64	100	-40 to +85	20-Lead TSSOP	RU-20	75
AD5253BRU100-RL7	64	100	-40 to +85	20-Lead TSSOP	RU-20	1,000
AD5253BRUZ100 ²	64	100	-40 to +85	20-Lead TSSOP	RU-20	75
AD5253BRUZ100-RL7 ²	64	100	-40 to +85	20-Lead TSSOP	RU-20	1,000
AD5253EVAL	64	10		Evaluation Board		1
AD5254BRU1	256	1	-40 to +85	20-Lead TSSOP	RU-20	75
AD5254BRU1-RL7	256	1	-40 to +85	20-Lead TSSOP	RU-20	1,000
AD5254BRUZ1 ²	256	1	-40 to +85	20-Lead TSSOP	RU-20	75
AD5254BRUZ1-RL7 ²	256	1	-40 to +85	20-Lead TSSOP	RU-20	1,000
AD5254BRU10	256	10	-40 to +85	20-Lead TSSOP	RU-20	75
AD5254BRU10-RL7	256	10	-40 to +85	20-Lead TSSOP	RU-20	1,000
AD5254BRUZ10 ²	256	10	-40 to +85	20-Lead TSSOP	RU-20	75
AD5254BRUZ10-RL7 ²	256	10	-40 to +85	20-Lead TSSOP	RU-20	1,000
AD5254BRU50	256	50	-40 to +85	20-Lead TSSOP	RU-20	75
AD5254BRU50-RL7	256	50	-40 to +85	20-Lead TSSOP	RU-20	1,000
AD5254BRUZ50 ²	256	50	-40 to +85	20-Lead TSSOP	RU-20	75
AD5254BRUZ50-RL7 ²	256	50	-40 to +85	20-Lead TSSOP	RU-20	1,000
AD5254BRU100	256	100	-40 to +85	20-Lead TSSOP	RU-20	75
AD5254BRU100-RL7	256	100	-40 to +85	20-Lead TSSOP	RU-20	1,000
AD5254BRUZ100 ²	256	100	-40 to +85	20-Lead TSSOP	RU-20	75
AD5254BRUZ100-RL7 ²	256	100	-40 to +85	20-Lead TSSOP	RU-20	1,000
AD5254EVAL	256	10		Evaluation Board		1

¹ In the package marking, Line 1 shows the part number. Line 2 shows the branding information, such that $B1 = 1 \text{ k}\Omega$, $B10 = 10 \text{ k}\Omega$, and so on. There is also a "#" marking for the Pb-free part. Line 3 shows the date code in YYWW. ² Z = Pb-free part.

NOTES

NOTES

NOTES

Purchase of licensed I²C components of Analog Devices or one of its sublicensed Associated Companies conveys a license for the purchaser under the Philips I²C Patent Rights to use these components in an I²C system, provided that the system conforms to the I²C Standard Specification as defined by Philips.

© 2005 Analog Devices, Inc. All rights reserved. Trademarks and registered trademarks are the property of their respective owners. D03824–0–9/05(A)



www.analog.com

Rev. A | Page 32 of 32